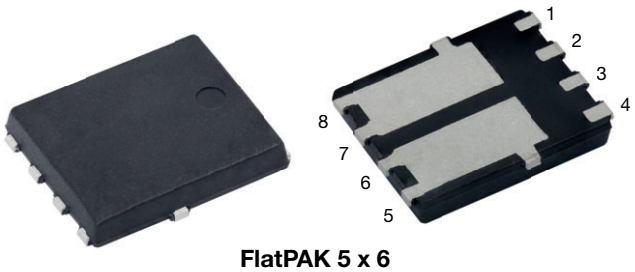
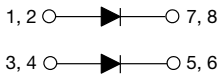
Hyper Fast Rectifier, 2 x 3 A FRED Pt®



FlatPAK 5 x 6



FEATURES

- Hyper fast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specific for output and snubber operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE Available

RoHS COMPLIANT

HALOGEN FREE

PRODUCT SUMMARY	
Package	FlatPAK 5 x 6
$I_{F(AV)}$	2 x 3 A
V_R	200 V
V_F at I_F	0.71 V
$t_{rr\ (typ.)}$	25 ns
T_J max.	175 °C
Diode variation	Separated cathode

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, piezo-injection, as high frequency rectifiers, and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: FlatPAK 5 x 6
Molding compound meets UL 94 V-0 flammability rating
Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V_{RRM}		200	V
Average rectified forward current	per device	$I_{F(AV)}$	$T_{Solderpad}$ = 170 °C, DC	6	A
			$T_{Solderpad}$ = 169 °C, D = 0.5		
Non-repetitive peak surge current	per device	I_{FSM}	T_J = 25 °C, 10 ms sinusoidal pulse	173	
	per diode			87	
Operating junction and storage temperatures		T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 µA	200	-	-	V
Forward voltage, per diode	V_F	I_F = 3 A	-	0.88	0.94	V
		I_F = 3 A, T_J = 150 °C	-	0.71	0.74	V
Reverse leakage current, per diode	I_R	V_R = V_R rated	-	-	2	µA
		T_J = 150 °C, V_R = V_R rated	-	2	40	µA
Junction capacitance	C_T	V_R = 200 V	-	14	-	pF

DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNITS**
Reverse recovery time	t_{rr}	I_F = 1.0 A, dI_F/dt = 50 A/µs, V_R = 30 V		-	20	-	ns
		I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A		-	-	25	ns
		T_J = 25 °C	I_F = 3 A dI_F/dt = 200 A/µs V_R = 160 V	-	15	-	ns
		T_J = 125 °C		-	25	-	ns
Peak recovery current	I_{RRM}	T_J = 25 °C		-	2	-	A
		T_J = 125 °C		-	3	-	A
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	12	-	nC
		T_J = 125 °C		-	40	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	175	°C
Thermal resistance, junction to ambient, per diode	R_{thJA} (1)(2)		-	90	103	°C/W
Thermal resistance, junction to case, per diode	R_{thJC} (3)		-	2.3	2.6	°C/W

Notes

(1) The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/ R_{thJA}$

(2) Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} - junction to ambient

(3) Mounted on infinite heatsink

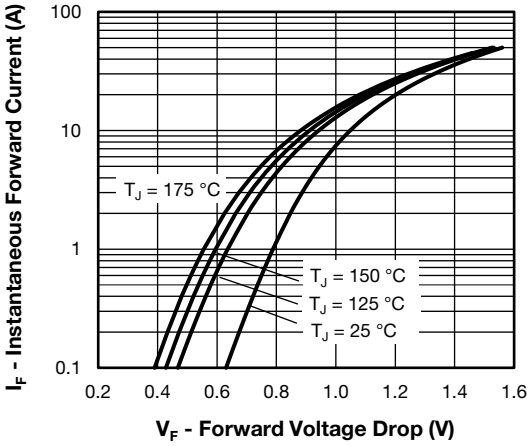


Fig. 1 - Typical Forward Voltage Drop Characteristics

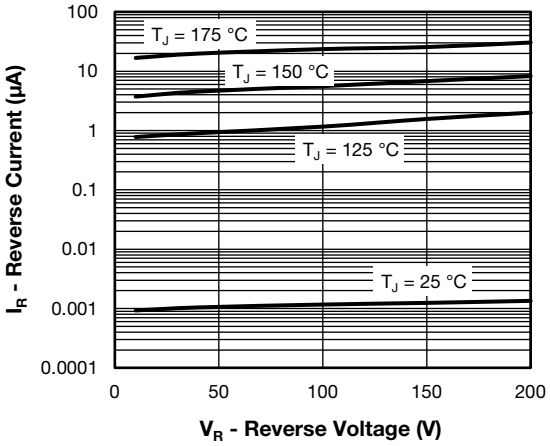


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

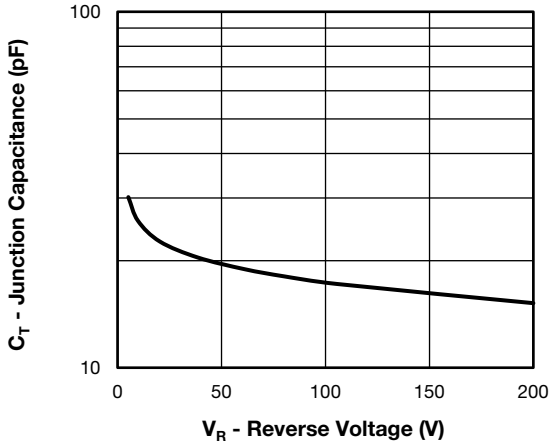


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

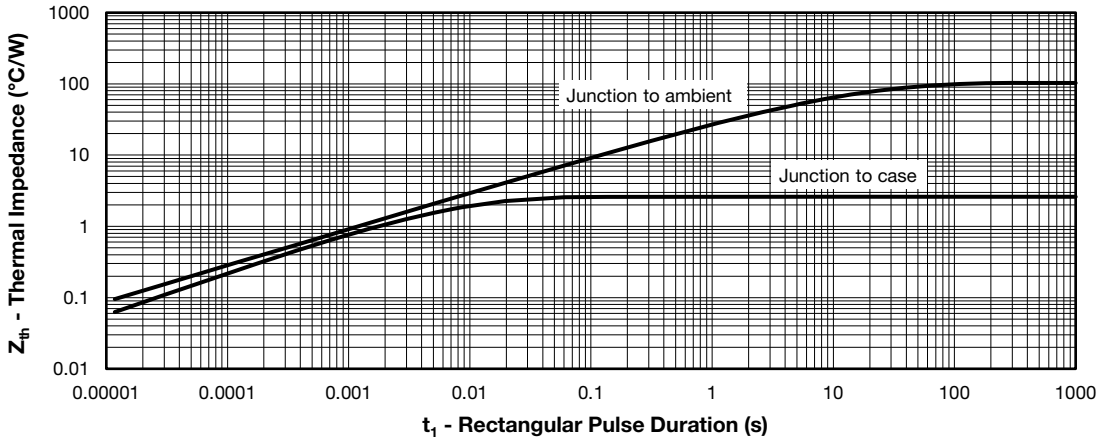


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

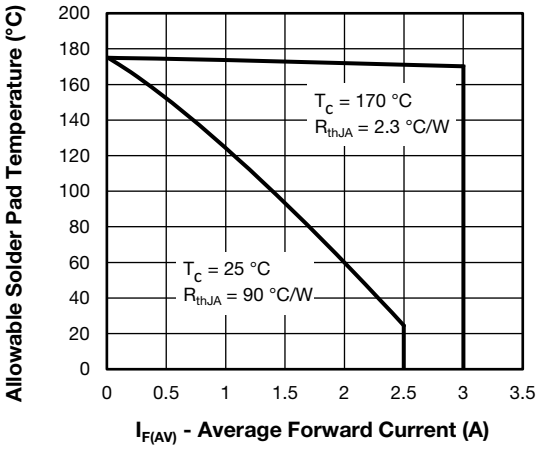


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

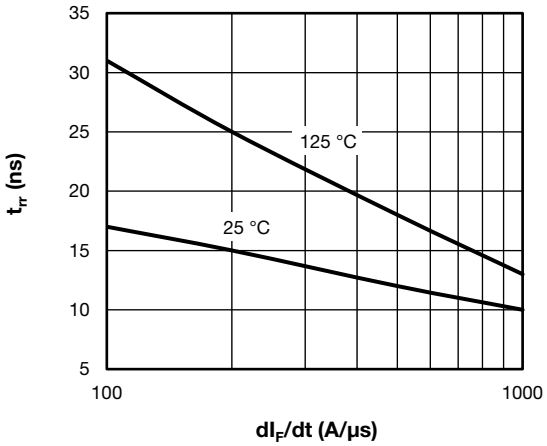


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

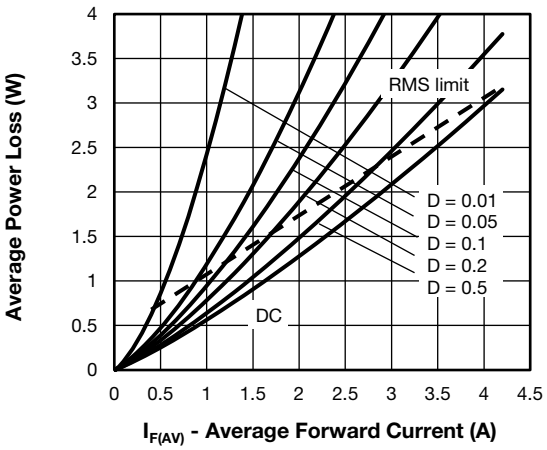


Fig. 6 - Forward Power Loss Characteristics

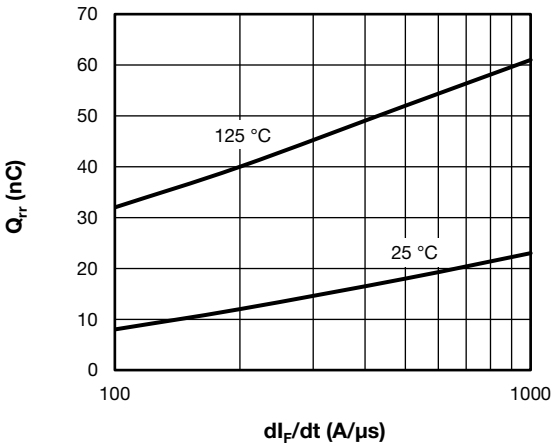
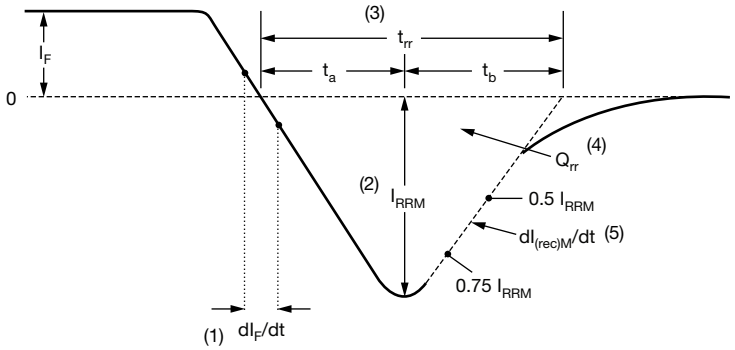


Fig. 8 - Typical Stored Charge vs. dI_F/dt



(1) dI_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

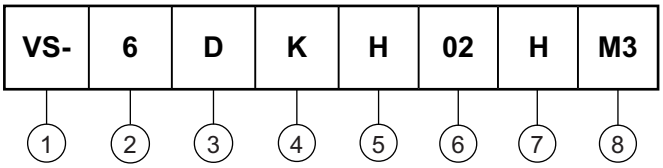
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product
2 - Current rating (6 = 6 A)
3 - Circuit configuration:
D = separated cathode
4 - K = FlatPAK package
5 - Process type,
H = hyperfast recovery
6 - Voltage code (02 = 200 V)
7 - H = AEC-Q101 qualified
8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (example)				
PREFERRED P/N	**UNIT WEIGHT (g)**	**PREFERRED PACKAGE CODE**	**BASE QUANTITY**	**PACKAGING DESCRIPTION**
VS-6DKH02HM3/H	0.10	H	1500	7"diameter plastic tape and reel
VS-6DKH02-M3/I	0.10	I	6000	13"diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96056
Part marking information	www.vishay.com/doc?96059
Packaging information	www.vishay.com/doc?88869

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